


SANYO Semiconductors

DATA SHEET

LA0152CS — Monolithic Linear IC For Ultra-small illumination Sensor Photo IC

Overview

The LA0152CS is a photo IC for micro-sized illumination sensor which has the characteristics of spectral response similar to that of human eyes. It is suitable for applications like mobile phone, laptop computer, PDA, DSC and Camcorder.

Characteristic

- Smallest OD-CSP package in the world (1.01mm x 1.01mm x thickness: 0.6mm)
- Low variation and Optical Output Current in low temperature fluctuation.
- Integrated Sleep function.
- Low current consumption.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC}		6	V
Operating temperature	T _{opr}		-30 to +85	°C
Storage temperature	T _{stg}		-40 to +100	°C

Recommended operating conditions and operating voltage range at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
SW pin low voltage	V _I	Sleep mode	0		0.4	V
SW pin high voltage	V _H	Active mode	1.4		V _{CC}	V

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

LA0152CS

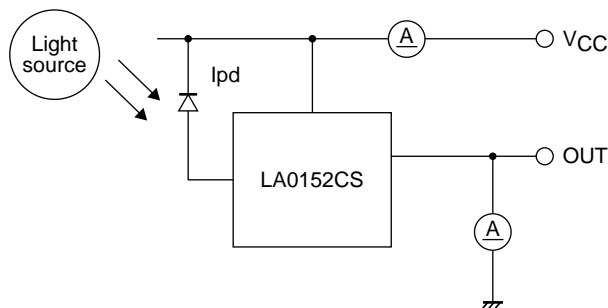
Electrical and optical characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 3.3\text{V}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Recommended Supply Voltage	V_{CC}		2.2	3.3	5.5	V
Current dissipation *1, *3	I_{CC}	$E_v = 1000 \text{ lx}$, $R_L = 5\text{k}\Omega$	90	150	210	μA
Sleep Current(1) *3	I_{SL1}	$E_v = 0 \text{ lx}$			0.1	μA
Sleep Current(1) *3	I_{SL2}	$E_v = 1000 \text{ lx}$			0.3	μA
Output current (2) *1, *3	I_{O1}	$E_v = 100 \text{ lx}$	6	8	10	μA
Output current (2) *1, *3	I_{O2}	$E_v = 1000 \text{ lx}$	60	80	100	μA
Dark current *3	I_{leak}	$E_v = 0 \text{ lx}$			0.1	μA
Temperature coefficient *2	I_{tc}	$E_v = 100 \text{ lx}$		0.34		$\% / ^\circ\text{C}$
Rise time *4	T_r	$E_v = 1000 \text{ lx}$, $R_L = 5\text{k}\Omega$		15	40	μs
Fall time *4	T_f	$E_v = 1000 \text{ lx}$, $R_L = 5\text{k}\Omega$		150	500	μs
Peak sensitivity wave length *2	λ_p			550		nm
Saturation output voltage *1, *3	V_O	$E_v = 1000 \text{ lx}$, $R_L = 150\text{k}\Omega$	3.0	3.2		V

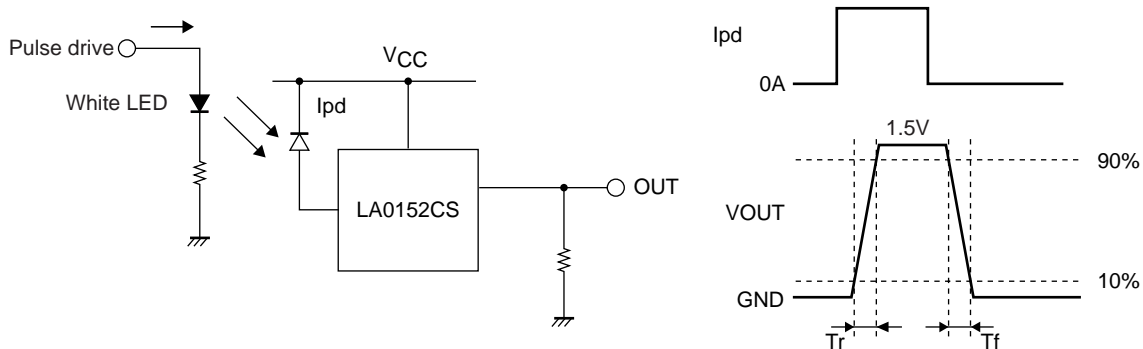
*1. Measured with the standard light source A. White LED is used instead in the mass production line.

*2. Design guaranteed item

*3. Test circuit for measuring current dissipation and output current

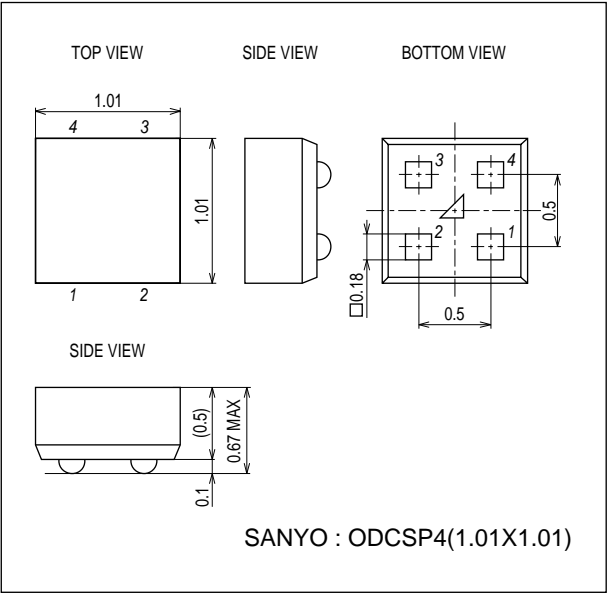


*4. Measuring method of rise time (T_r) and fall time (T_f)

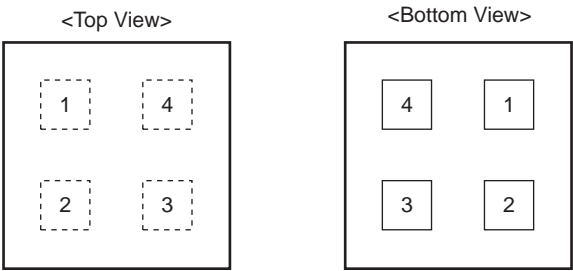


Package Dimensions

unit : mm (typ)
3350A



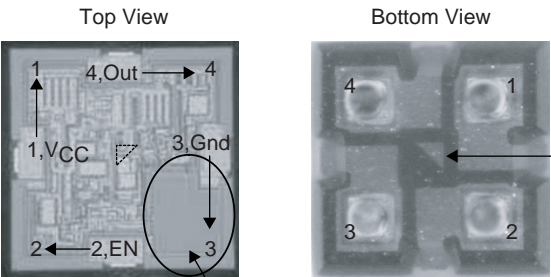
Pad layout



Pin No.	Pin Name	Function
1	VCC	Power supply
2	EN	Enable
3	GND	Ground
4	OUT	Output

Ball pitch : 0.5mm, Ball size : 0.18mm[□]

Pad layout (Photos)

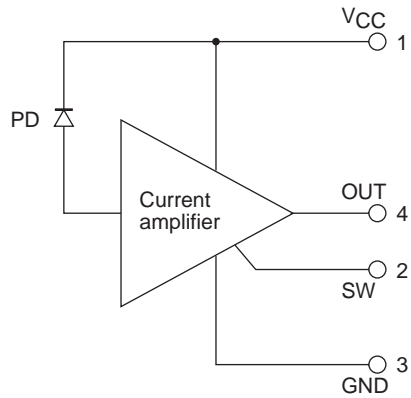


Pin 1 mark
It is located at the center of the bottom of the package.

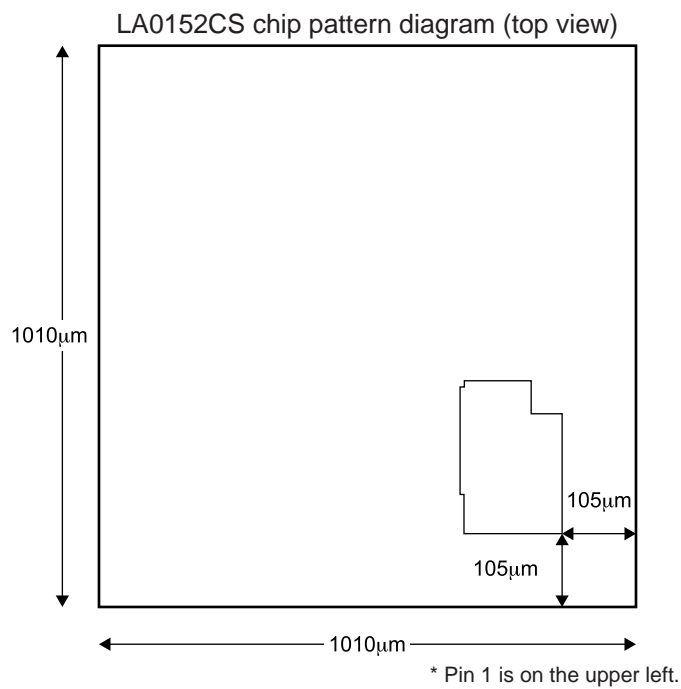
Photo diode. Only this part looks dark on the product.

* The photo diode is located in pin 3. Be careful not to mistake the pin 1 mark for the photo diode.

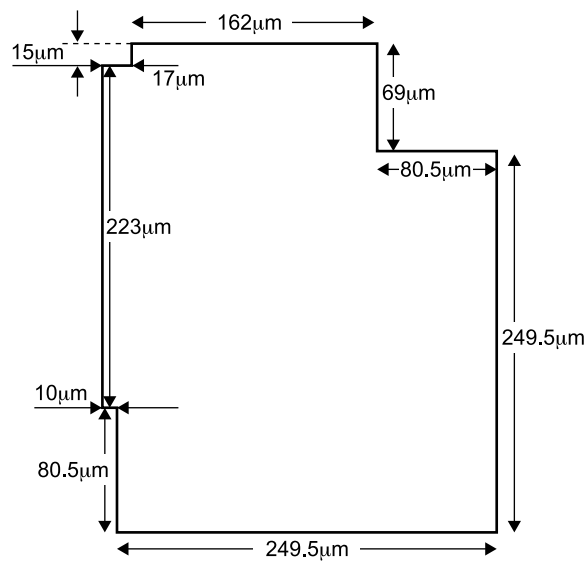
Internal block diagram

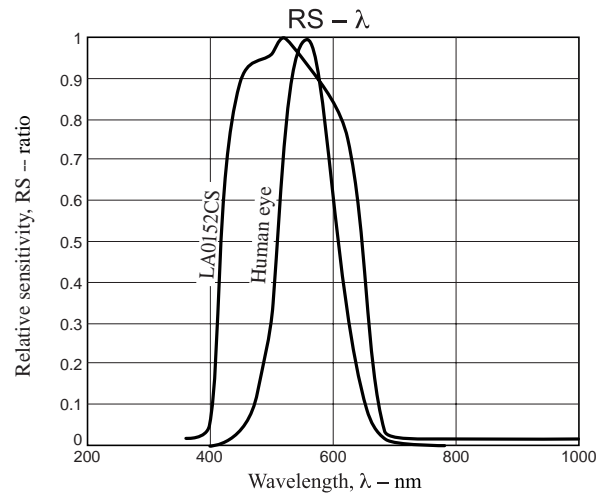
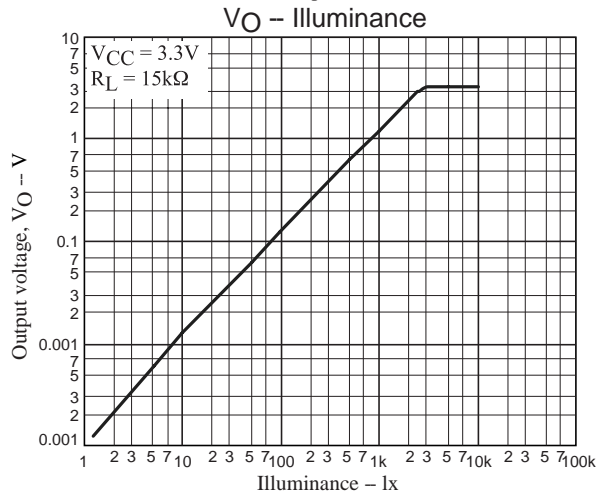
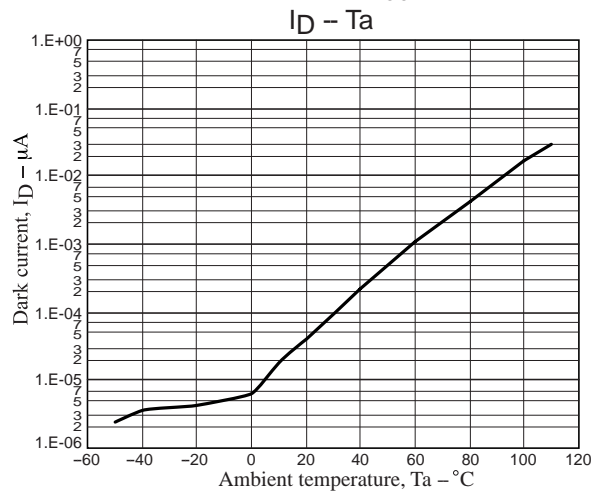
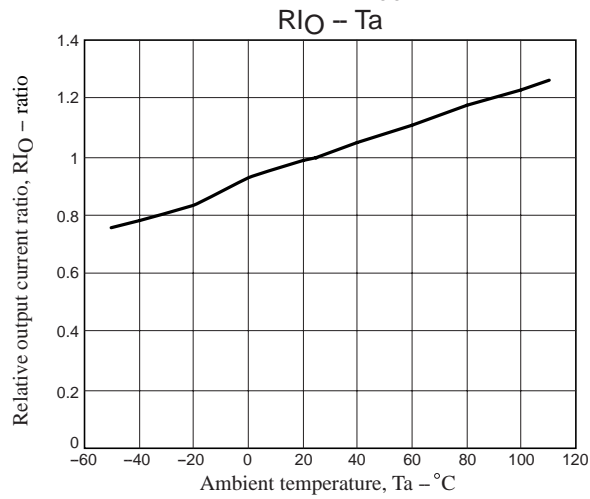
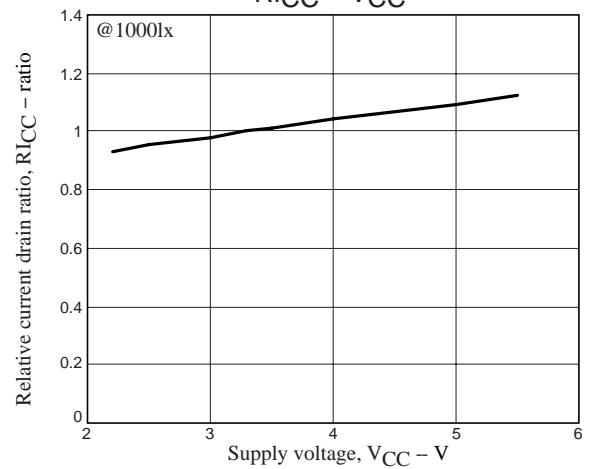
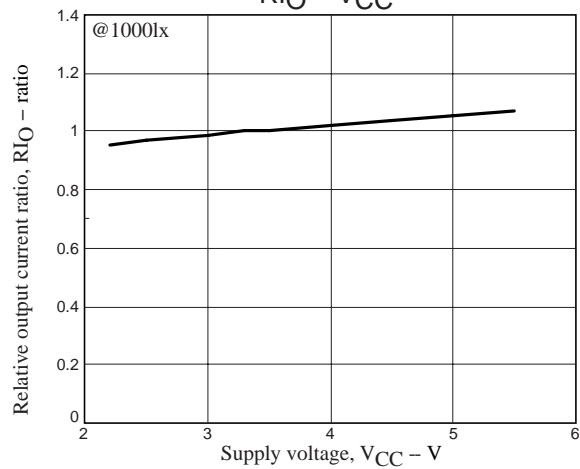
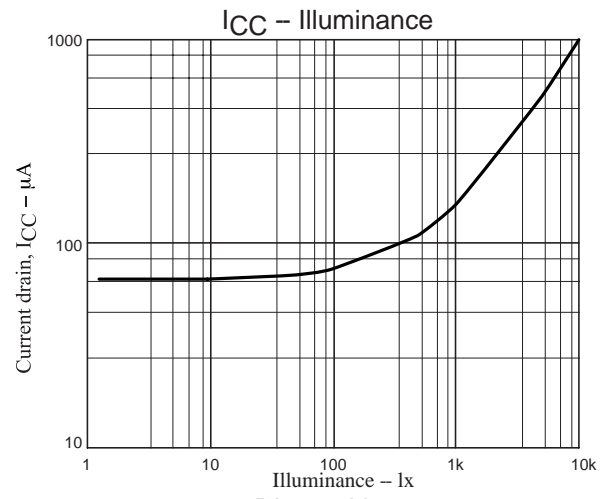
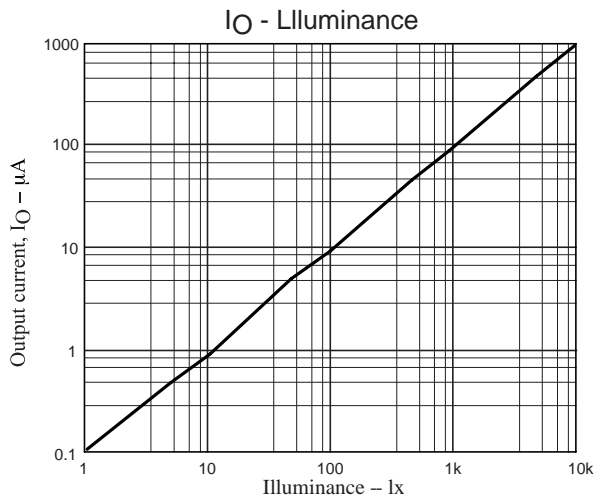


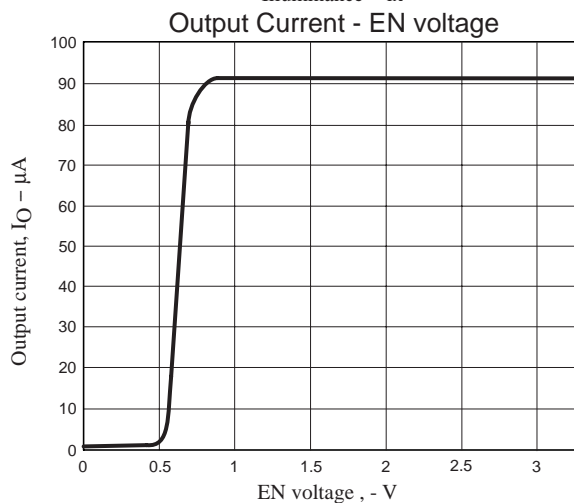
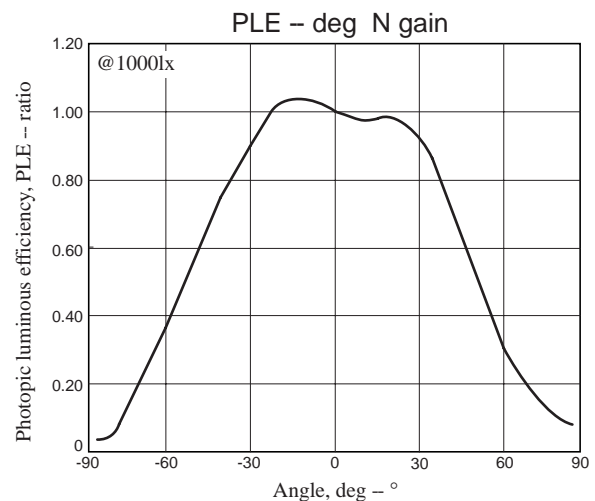
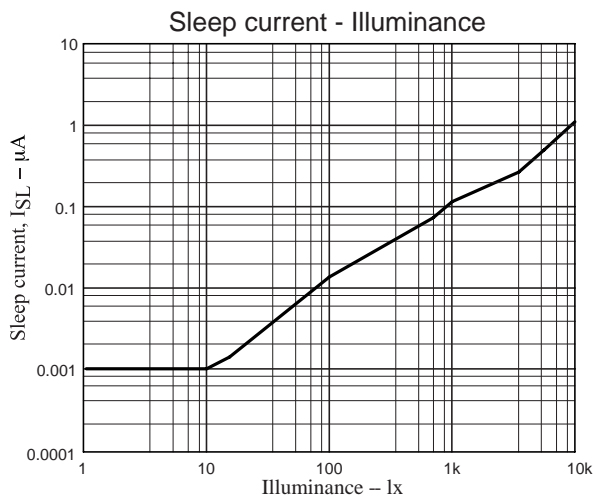
Chip pattern and photo-receiving pattern diagrams



LA0152CS photo-receiving pattern enlarged diagram (effective area)







- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of December, 2009. Specifications and information herein are subject to change without notice.